

## WBFBP-03E Plastic-Encapsulate Diodes

### ESDBL5V0F2 ESD PROTECTION DIODE

#### DESCRIPTION

The ESDBL5V0F2 is a transient voltage suppressors (TVS) which provide a very high level protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). It is designed to replace multiplayer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

#### FEATURES

- Low reverse stand-off voltage: 5 V
- Low leakage current
- Ultra-low clamping voltage
- IEC 61000-4-2 level 4 ESD protection
- This is Pb-free device

#### APPLICATIONS

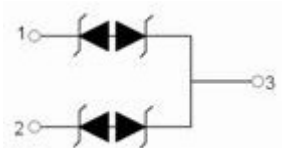
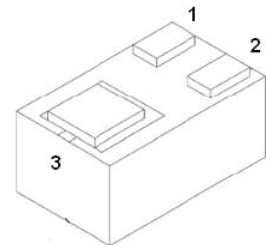
- Mobile phone
- PAD
- Notebook
- STB
- LCD TV
- Digital camera
- Other electronics equipments Communication systems

#### MARKING: H



TOP VIEW

WBFBP-03E



**MAXIMUM RATINGS (  $T_a=25^{\circ}\text{C}$  unless otherwise noted )**

Parameter	Symbol	Limit	Unit
Electrostatic Discharge Voltage( IEC61000-4-2) (Note 1)	Air Model	$\pm 30$	kV
	Contact Model	$\pm 30$	
	Per Human Body Model	16	
	Machine Model	400	V
Peak Pulse Power (8/20 $\mu\text{s}$ Waveform) (Note 2)	$P_{PP}$	62.5	W
Peak Pulse Current (8/20 $\mu\text{s}$ Waveform) (Note 2)	$I_{PP}$	5	A
Lead Solder Temperature – Maximum (10 Second Duration)	$T_L$	260	$^{\circ}\text{C}$
Junction Temperature	$T_j$	150	$^{\circ}\text{C}$
Storage Temperature Range	$T_{stg}$	-55 ~ +150	$^{\circ}\text{C}$

Note:

(1).Device stressed with ten non-repetitive ESD pulses.

(2).Non-repetitive current pulse 8/20 $\mu\text{s}$  exponential decay waveform according to IEC61000-4-5.

Stresses exceeding maximum ratings may damage the device. Maximum ratings are stress ratings only. Functional operation above the recommended. Operating conditions is not implied. Extended exposure to stresses above the recommended operating conditions may affect device reliability.

**ELECTRICAL PARAMETER**

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current

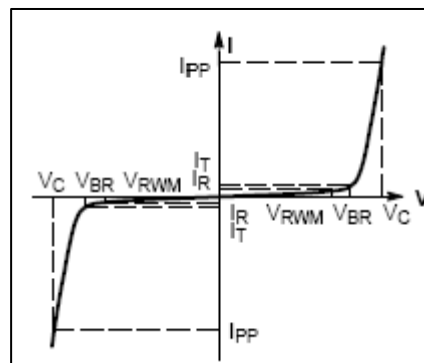


Fig 1. V-I characteristics for a bi-directional TVS

**ELECTRICAL CHARACTERISTICS( $T_a=25^{\circ}\text{C}$  unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand off voltage	$V_{RWM}^{(1)}$				5	V
Breakdown voltage	$V_{(BR)}$	$I_T=1\text{mA}$	5.8		8	V
Reverse current	$I_R$	$V_{RWM}=5\text{V}$			0.1	$\mu\text{A}$
Clamping voltage	$V_C^{(2)}$	$I_{PP}=5\text{A}$			12.5	V
Total capacitance	$C_{tot}$	$V_R=0\text{V}, f=1\text{MHz}$		10		pF

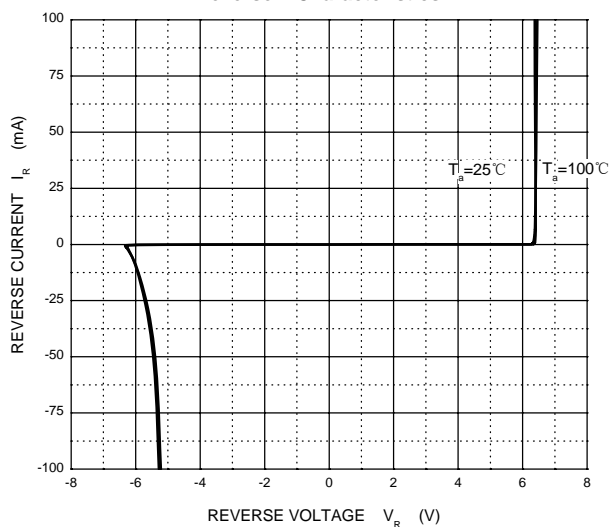
(1).Other voltages available upon request.

(2).Non-repetitive current pulse 8/20 $\mu\text{s}$  exponential decay waveform according to IEC61000-4-5.

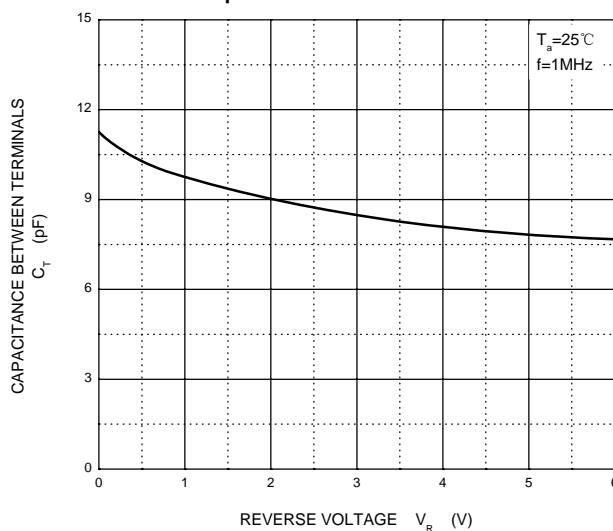


# ESDBL5V0F2

Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

